

#### DESCRIPTION

The SPN8668 is the N-Channel logic enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology.

This high density process is especially tailored to minimize on-state resistance.

These devices are particularly suited for low voltage application, notebook computer power management and other battery powered circuits where high efficiency and fast switching is required.

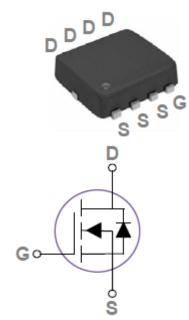
#### FEATURES

- 60V/80A, RDS(ON)= $21m\Omega(a)$ VGS=10V
- 60V/80A, RDS(ON)= $24m\Omega(a)VGS$ =4.5V
- Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- PPAK3x3-8L package design

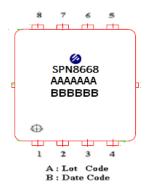
### APPLICATIONS

- Motor Drive
- Power Tools
- LED Lighting

#### PIN CONFIGURATION(PPAK3x3-8L)



PART MARKING





PIN DESCRIPTION					
Pin	Symbol	Description			
1	S	Source			
2	S	Source			
3	S	Source			
4	G	Gate			
5	D	Drain			
6	D	Drain			
7	D	Drain			
8	D	Drain			

#### ORDERING INFORMATION

Part Number	Package	Part Marking	
SPN8668DN8RGB	PPAK3x3-8L	SPN8668	

X SPN8668DN8RGB : 13" Tape Reel ; Pb – Free; Halogen - Free

## ABSOULTE MAXIMUM RATINGS

(TA=25°C Unless otherwise noted)

Parameter		Symbol	Typical	Unit
Drain-Source Voltage		Vdss	60	V
Gate –Source Voltage		VGSS	±20	V
	Tc=25°C	T-	80	
Continuous Drain Current(TJ=150°C)	Tc=100°C	ID	57	A
Pulsed Drain Current	Idм	132	А	
Continuous Source Current(Diode Conduction)		Is	33	А
Power Dissipation	TA=25°C	PD	7	W
Operating Junction Temperature	τı	-55/150	°C	
Storage Temperature Range		Tstg	-55/150	°C
Thermal Resistance-Junction to Ambient		Reja	62	°C/W
Thermal Resistance-Junction to Case		Rөjc	2.8	°C/W

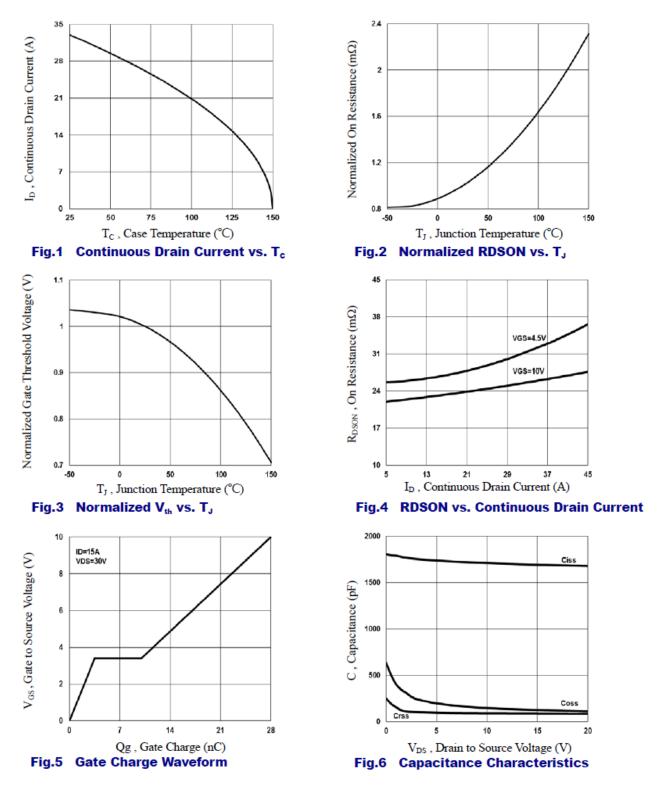


## ELECTRICAL CHARACTERISTICS

(TA=25°C Unless otherwise noted)

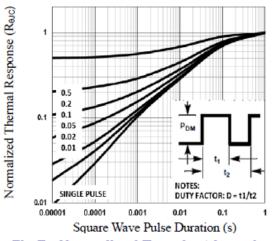
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit	
Static		·				·	
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V, ID=250uA	60			v	
Gate Threshold Voltage	VGS(th)	VDS=VGS, IDS=25uA	1.2	1.8	2.2	v	
Gate Leakage Current	Igss	Vds=0V, Vgs=±20V			±100	nA	
	Idss	VDS=60V,VGS=0V, TJ=25°C			1		
Zero Gate Voltage Drain Current	IDSS	Vds=48V,Vgs=0V, Tj=125°C			10	- uA	
Drain-Source On-Resistance	RDS(on)	Vgs=10V, Id=15A		17	21		
Drain-Source On-Resistance	<b>K</b> DS(on)	Vgs=4.5V, Id=8A		20	24	mΩ	
Forward Transconductance	gfs	Vds=10V, Id=10A		9		S	
Diode Forward Voltage	Vsd	IF=1A,VGS=0V			1	V	
Dynamic							
Total Gate Charge	Qg			28	42	nC	
Gate-Source Charge	Qgs	VDS=30V,VGS=10V, ID=15A		3.5	7		
Gate-Drain Charge	Qgd	1D-13A		6.5	10		
Input Capacitance	Ciss			1680	2440	pF	
Output Capacitance	Coss	Vgs=0V, Vds=20V, F=1MHz		115	170		
Reverse Transfer Capacitance	Crss	1'—11V111Z		85	125		
Turn-On Time	td(on)			7.2	14	- ns	
	tr	(VDD=30V,ID=-1A,		38	72		
	td(off)	$V_{\text{GEN}}=10V, R_{\text{G}}=6\Omega)$		34	65		
Turn-Off Time	tf	1		8.2	16		

#### TYPICAL CHARACTERISTICS

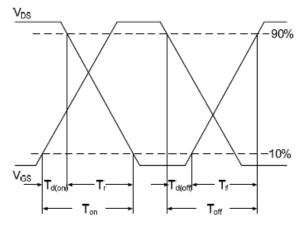


2018/3/22 Ver 1

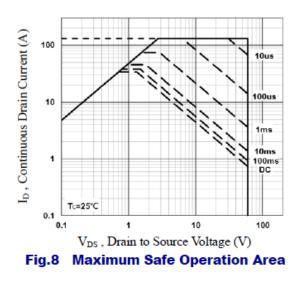
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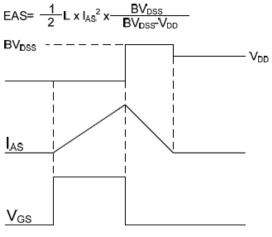






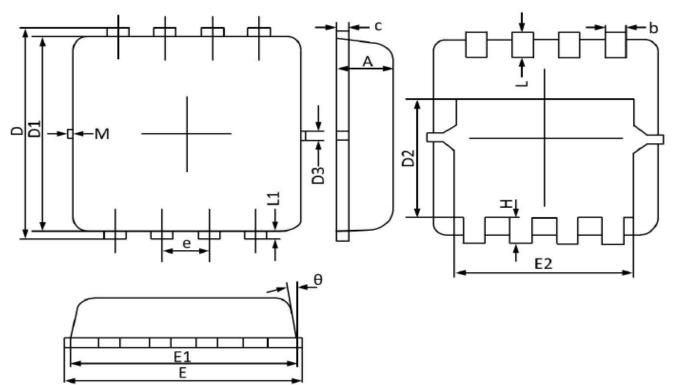








### PPAK3x3-8L PACKAGE OUTLINE



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	0.700	0.800	0.028	0.031	
b	0.250	0.350	0.010	0.013	
c	0.100	0.250	0.004	0.009	
D	3.250	3.450	0.128	0.135	
D1	3.000	3.200	0.119	0.125	
D2	1.780	1.980	0.070	0.077	
D3	0.130 REF		0.005 REF		
E	3.200	3.400	0.126	0.133	
E1	3.000	3.200	0.119	0.125	
E2	2.390	2.590	0.094	0.102	
e	0.650 BSC		0.026 BSC		
Н	0.300	0.500	0.011	0.019	
L	0.300	0.500	0.011	0.019	
L1	0.130 REF		0.005 REF		
θ	0°	12°	0°	12°	
М	0.150 REF		0.006 REF		



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